# Nanostack Pulsed Laser Diode Version 1.1

# SPL DS90\_3



### Features:

- Reliable strained InGaAs/GaAs material
- High power large-optical-cavity structure
- · Nanostack laser technology including multiple epitaxially stacked emitters
- Laser aperture 200  $\mu m \times 10 \ \mu m$

### Applications

- Range finding
- Security, surveillance
- Illumination, ignition
- Testing and measuring applications

#### Notes

Depending on the mode of operation, these devices emit highly concentrated non visible infrared light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1 and IEC 62471.

### **Ordering Information**

Туре:	Peak wavelength	Ordering Code
	(typ) λ <sub>peak</sub>	
SPL DS90_3	903	Q65111A5640



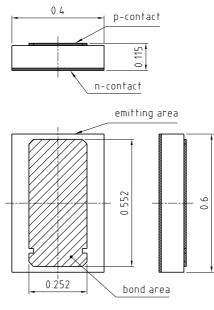
# Version 1.1

# Characteristics (T<sub>A</sub> = 25 $^{\circ}$ C)

Parameter	Symbol	Values			Unit
		min	typ	max	
Number of vertically stacked emitters			3		
Standard pulse center wavelength	$\lambda_{pulse}$	897	903	909	nm
Threshold current	I <sub>th</sub>		0.55	0.7	А
Differential efficiency	η	3.5	3.7		W / A
Aperture size	w x h		200 x 10		μm x μm
Beam divergence (FWHM) perpendicular to pn-junction	Θ		25	30	0
Beam divergence (FWHM) parallel to pn-junction	Θ <sub>II</sub>		10		0
Differential series resistance	R <sub>s</sub>		0.32	0.4	Ω
Characteristic temperature (threshold) <sup>1) page 4</sup>	T <sub>o</sub>	100	115		к

Note: All characteristics and limitations refer to pulsed measurements (1µs pulse wifth at 1kHz repetition rate) on unmounted laser dice. For exemplary characteristicals of laser operation in plastic package see datasheet SPL PL90\_3.

## Chip Outlines (Dimensions in mm)



In this drawing only essential parameters are included

C63062-A4249-A1-01



## Disclaimer

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

#### Attention please!

The information describes the type of component and shall not be considered as assured characteristics.

Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version in the Internet.

#### Packing

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\*\*) Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health and the life of the user may be endangered.



# Glossary

<sup>1)</sup> Thermal behavior: Model for the thermal behavior of threshold current:  $I_{th}$  ( $T_2$ ) =  $I_{th}$ ( $T_1$ ) x exp ( $T_2$  - $T_1$ ) /  $T_0$ 

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